


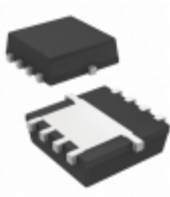





	<h2 style="color: red;">SI7613DN-T1-GE3</h2>
	<b>Hersteller-Teilenummer:</b> <a href="#">SI7613DN-T1-GE3</a>
	<b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a>
	<b>Teil der Beschreibung:</b> MOSFET P-CH 20V 35A 1212-8 PPAK
	<b>Datenblätter:</b>  <a href="#">SI7613DN-T1-GE3.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 43626 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI7613DN-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET P-CH 20V 35A 1212-8 PPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	43626 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-50°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® 1212-8
Supplier Device-Gehäuse	PowerPAK® 1212-8
Verlustleistung (max)	3.8W (Ta), 52.1W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	35A (Tc)
Rds On (Max) @ Id, Vgs	8.7 mOhm @ 17A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	87nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2620pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±16V
Verpackung	Tape & Reel (TR)





















SI7613DN-T1-GE3 ist neu im Original, Suche SI7613DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7613DN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7613DN-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI7613DN-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 35A 1212-8 PPAK</p>	 <p><b>SI7615ADN-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 35A 1212-8S</p>	 <p><b>SI7615ADN-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 35A 1212-8S</p>	 <p><b>SI7611DN</b> SI SI7611DN SI</p>
 <p><b>SI7613DN-T1-E3</b> VISHAY VISHAY PAK1212</p>	 <p><b>SI7611DN-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 40V 18A 1212-8</p>	 <p><b>SI7611DN-T1-E3</b> VISHAY SI7611DN-T1-E3 VISHAY</p>	 <p><b>SI7615ADN-T1-E3</b> VISHAY VISHAY PAK1212</p>

### heiße Teile

Mehr

 SI7483DP-T1-E3	 SI7483DP-T1-GE3	 SI7485DP-T1-E3	 SI7485DP-T1-E3	 SI7485DP-T1-GE3
 SI7485DP-T1-GE3	 SI7489DP	 SI7489DP-T1-GE3	 SI7489DP-T1-GE3	 SI7491DP
 SI7491DP-T1-GE3	 SI7491DP-T1-GE3	 SI7501DN-T1-E3	 SI7501DN-T1-E3	 SI7540ADP-T1-GE3
 SI7540ADP-T1-GE3	 SI7540DP-T1-E3	 SI7540DP-T1-E3	 SI7540DP-T1-GE3	 SI7540DP-T1-GE3
 SI7606DN-T1-E3	 SI7606DN-T1-GE3	 SI7611DN-T1-GE3	 SI7611DN-T1-GE3	 SI7613DN-T1-GE3
 SI7615ADN-T1-GE3	 SI7615ADN-T1-GE3	 SI7615DN	 SI7615DN-T1-E3	 SI7615DN-T1-GE3
 SI7615DN-T1-GE3	 SI7617DN-T1-GE3	 SI7617DN-T1-GE3	 SI7619DN-T1-GE3	 SI7619DN-T1-GE3
 SI7621DN-T1-GE3	 SI7621DN-T1-GE3	 SI7625DN-T1-GE3	 SI7625DN-T1-GE3	 SI7629DN-T1
 SI7629DN-T1-GE3	 SI7629DN-T1-GE3	 SI7633DP-T1-GE3	 SI7633DP-T1-GE3	 SI7634BDP
 SI7634BDP-T1-E3	 SI7634BDP-T1-E3	 SI7634BDP-T1-GE3	 SI7634BDP-T1-GE3	 SI7634DP-T1-E3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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